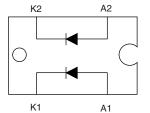


Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 60 A

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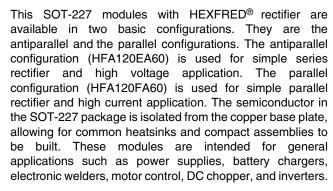
SOT-227

PRODUCT SUMMARY					
V_{R}	600 V				
V _F (typical) at 125 °C	1.4 V				
Q _{rr} (typical)	270 nC				
I _{RRM} (typical)	7.0 A				
t _{rr} (typical)	65 ns				
dl _{(rec)M} /dt (typical) at 125 °C	270 A/μs				
I _{F(DC)} at T _C	40 A at 100 °C				

FEATURES

- Fast recovery time characteristic
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · UL pending
- Totally lead (Pb)-free
- · Designed for industrial level

DESCRIPTION



ABSOLUTE MAXIMUM RATINGS PER LEG					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		600	V	
Outliness forward assess		T _C = 25 °C	75		
Continuous forward current	IF	T _C = 100 °C	40	_	
Single pulse forward current	I _{FSM}		TBD	A	
Maximum repetitive forward current	I _{FRM}		180		
RMS isolation voltage, any terminal to case	V_{ISOL}	t = 1 minute	2500	V	
Maximum power dissipation	P _D	T _C = 25 °C	180	W	
		T _C = 100 °C	71	VV	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C	

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA		600	-	-	
Maximum forward voltage V _{FM}		I _F = 60 A	See fig. 1	=	1.5	1.7	V
	V_{FM}	I _F = 120 A		-	1.9	2.1	
		I _F = 60 A, T _J = 125 °C		=	1.4	1.6	
Maximum reverse leakage current I _{RI}	I _{RM}	$V_R = V_R$ rated	See fig. 2	=	2.5	20	- μΑ
		$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 ^{\circ}\text{x} ^{\circ}\text{V}_R ^{\circ}\text{rated}$		=	130	2000	
Junction capacitance	C _T	V _R = 200 V	See fig. 3	-	120	170	pF

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DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	/μs, V _R = 30 V	-	34	-	
Reverse recovery time See fig. 5, 6 and 16	t _{rr1}	T _J = 25 °C		-	65	98	ns
coo ng. o, o and ro	t _{rr2}	T _J = 125 °C		-	130	200	
Peak recovery current	I _{RRM1}	T _J = 25 °C	$I_F = 60 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	7.0	13	A
See fig. 7 and 8	I _{RRM2}	T _J = 125 °C		-	13	23	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	270	410	nC
See fig. 9 and 10	Q _{rr2}	T _J = 125 °C		-	490	740	iiC
Peak rate of recovery current during t _b See fig. 11 and 12	dI _{(rec)M} /dt1	T _J = 25 °C		-	350	-	A/110
	dI _{(rec)M} /dt2	T _J = 125 °C		-	270	-	A/μs

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Junction to case, single leg conducting	В	-	-	0.70	0000	
Junction to case, both legs conducting	R _{thJC}	-	-	0.35	°C/W K/W	
Case to sink, flat, greased surface	R _{thCS}	-	0.05	-		
Weight		-	30	-	g	
Mounting torque		-	1.3	-	Nm	



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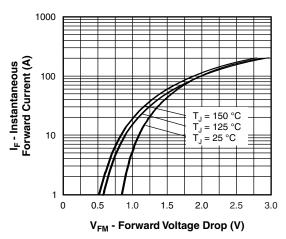


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

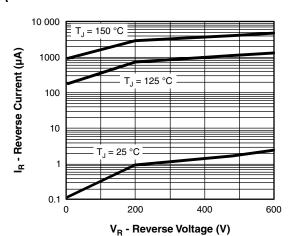


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

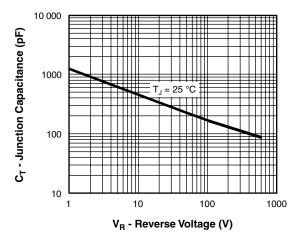


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

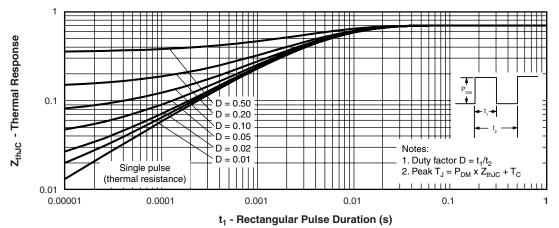


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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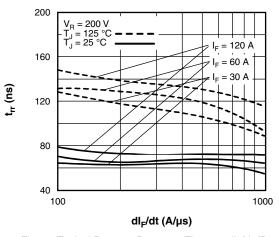


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)

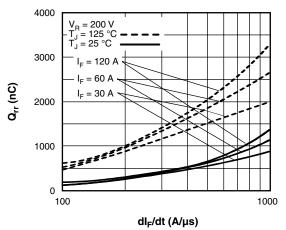


Fig. 7- Typical Stored Charge vs. dI_F/dt (Per Leg)

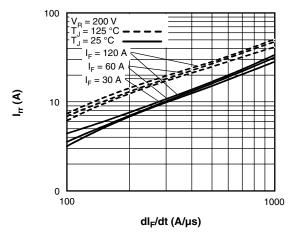


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

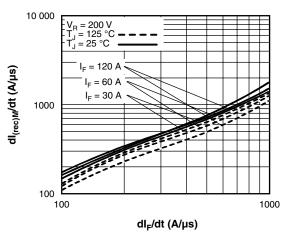


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)



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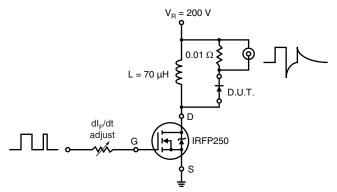
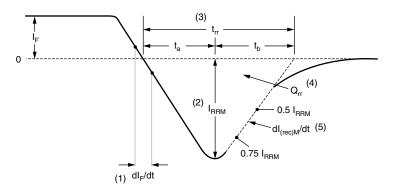


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) $\rm I_{RRM}$ peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

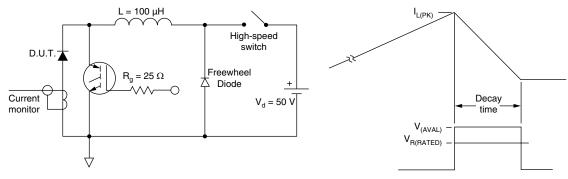


Fig. 11 - Avalanche Test Circuit and Waveforms

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ORDERING INFORMATION TABLE

1 - HEXFRED® family

2 - Process: A electron irradiated

3 - Current rating (120 = 120 A)

4 - Package indicator (SOT-227)

5 - Voltage rating (60 = 600 V)

6 - P = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95036				
Packaging information	http://www.vishay.com/doc?95037			



Vishay

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